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"Embedded - Microcontrollers" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "Embedded - Microcontrollers"

Details	
Product Status	Obsolete
Core Processor	M16C/60
Core Size	16-Bit
Speed	16MHz
Connectivity	I²C, IEBus, UART/USART
Peripherals	DMA, POR, PWM, WDT
Number of I/O	85
Program Memory Size	192KB (192K x 8)
Program Memory Type	FLASH
EEPROM Size	4K x 8
RAM Size	6K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 18x10b
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-BQFP
Supplier Device Package	100-QFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/m30302fepfp-u3

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1. Overview

The M16C/30P Group of single-chip microcomputers is built using the high-performance silicon gate CMOS process using a M16C/60 Series CPU core and is packaged in a 100-pin plastic molded QFP.
These single-chip microcomputers operate using sophisticated instructions featuring a high level of instruction efficiency. With 1 Mbyte of address space, they are capable of executing instructions at high speed. In addition, these microcomputers contain a multiplier and DMAC which combined with fast instruction processing capability, make it suitable for control of various OA, communication, and industrial equipment which requires high-speed arithmetic/logic operations.

1.1 Applications

Audio, cameras, TV, home appliance, office/communications/portable/industrial equipment, etc.

1.4 Product List

Table 1.2 lists the M16C/30P group products and Figure 1.2 shows the Part No., Memory Size, and Package. Table 1.4 lists Product Code of MASK ROM version for M16C/30P. Figure 1.3 shows the Marking Diagram of Mask ROM Version for M16C/30P (Top View). Table 1.5 lists Product Code of One Time Flash version, Flash Memory version, and ROM-less version for M16C/30P. Figure 1.4 shows the Marking Diagram of One Time Flash version, Flash Memory version, and ROM-less Version for M16C/30P (Top View). Please specify the marking for M16C30P (MASK ROM version) when placing an order for ROM.

Table 1.2 Product List (1) **As of March 2007**

Part No.	ROM Capacity	RAM Capacity	package code (1)	Remarks
M30302MAP-XXXFP	96 Kbytes	5 Kbytes	PRQP0100JB-A	Mask ROM version
M30302MAP-XXXGP			PLQP0100KB-A	
M30302MCP-XXXFP	128 Kbytes		PRQP0100JB-A	
M30302MCP-XXXGP			PLQP0100KB-A	
M30302MDP-XXXFP	160 Kbytes	6 Kbytes	PRQP0100JB-A	
M30302MDP-XXXGP			PLQP0100KB-A	
M30302MEP-XXXFP	192 Kbytes		PRQP0100JB-A	
M30302MEP-XXXGP			PLQP0100KB-A	
M30302GAPFP	96 Kbytes	5 Kbytes	PRQP0100JB-A	One Time Flash version (blank product)
M30302GAPGP (D)			PLQP0100KB-A	
M30302GCPFP	128 Kbytes		PRQP0100JB-A	
M30302GCPGP (D)			PLQP0100KB-A	
M30302GDPFP	160 Kbytes	6 Kbytes	PRQP0100JB-A	
M30302GDPGP (D)			PLQP0100KB-A	
M30304GDPFP (D)		12 Kbytes	PRQP0100JB-A	
M30304GDPGP (D)			PLQP0100KB-A	
M30302GEPFP	192 Kbytes	6 Kbytes	PRQP0100JB-A	
M30302GEPGP (D)			PLQP0100KB-A	
M30304GEPFP (D)		12 Kbytes	PRQP0100JB-A	
M30304GEPGP (D)			PLQP0100KB-A	
M30302GGPFP (D)	256 Kbytes	12 Kbytes	PRQP0100JB-A	
M30302GGPGP (D)			PLQP0100KB-A	
M30302GAP-XXXFP	96 Kbytes	5 Kbytes	PRQP0100JB-A	One Time Flash version (factory programmed product)
M30302GAPvGP (D)			PLQP0100KB-A	
M30302GCP-XXXFP	128 Kbytes		PRQP0100JB-A	
M30302GCP-XXXGP (D)			PLQP0100KB-A	
M30302GDP-XXXFP	160 Kbytes	6 Kbytes	PRQP0100JB-A	
M30302GDP-XXXGP (D)			PLQP0100KB-A	
M30304GDP-XXXFP (D)		12 Kbytes	PRQP0100JB-A	
M30304GDP-XXXGP (D)			PLQP0100KB-A	
M30302GEP-XXXFP	192 Kbytes	6 Kbytes	PRQP0100JB-A	
M30302GEP-XXXGP (D)			PLQP0100KB-A	
M30304GEP-XXXFP (D)		12 Kbytes	PRQP0100JB-A	
M30304GEP-XXXGP (D)			PLQP0100KB-A	
M30302GGP-XXXFP (D)	256 Kbytes	12 Kbytes	PRQP0100JB-A	
M30302GGP-XXXGP (D)			PLQP0100KB-A	

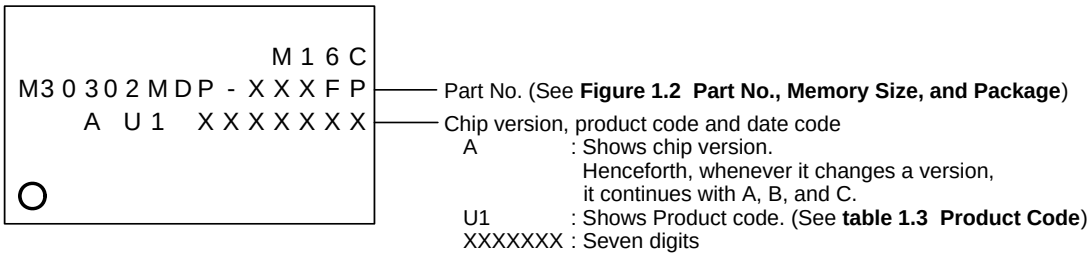
(D): Under development
(P): Under planning
NOTES:
1. Previous package codes are as follows.
   PRQP0100JB-A : 100P6S-A,
   PLQP0100KB-A : 100P6Q-A
2. Block A (4-Kbytes space) is available in flash memory version.

Table 1.4 Product Code of MASK ROM version for M16C/30P

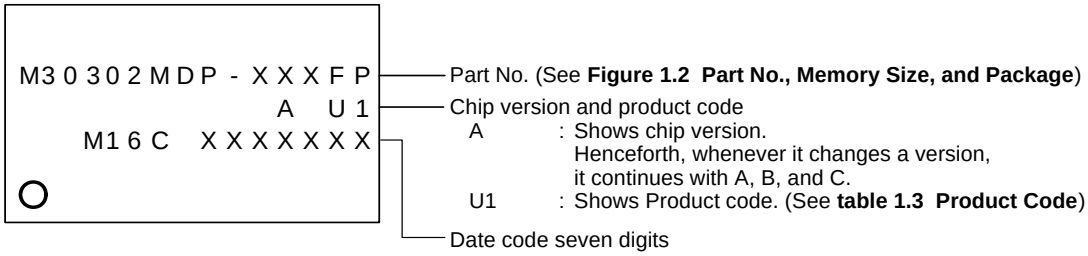
Product Code	Package	Operating Ambient Temperature
U1	Lead-free	-20°C to 85°C
U4		-40°C to 85°C

PRQP0100JB-A (100P6S-A)

1. Standard Renesas Mark

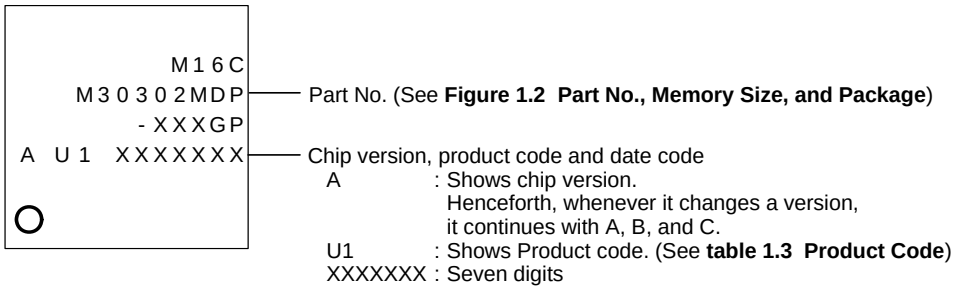


2. Customer's Parts Number + Renesas catalog name

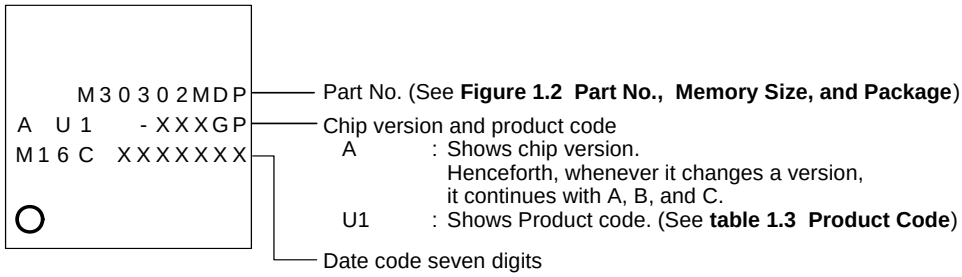


PLQP0100KB-A (100P6Q-A)

1. Standard Renesas Mark



2. Customer's Parts Number + Renesas catalog name



NOTES:
1. Refer to the **mark specification form** for details of the Mask ROM version marking.

Figure 1.3 Marking Diagram of Mask ROM Version for M16C/30P (Top View)

Table 1.6 Pin Characteristics (1)

Pin No.		Control Pin	Port	Interrupt Pin	Timer Pin	UART Pin	Analog Pin	Bus Control Pin
FP	GP							
1	99		P9_6				ANEX1	
2	100		P9_5				ANEX0	
3	1		P9_4					
4	2		P9_3					
5	3		P9_2		TB2IN			
6	4		P9_1		TB1IN			
7	5		P9_0		TB0IN			
8	6	BYTE						
9	7	CNVSS						
10	8	XCIN	P8_7					
11	9	XCOUT	P8_6					
12	10	$\overline{\text{RESET}}$						
13	11	XOUT						
14	12	VSS						
15	13	XIN						
16	14	VCC1						
17	15		P8_5	$\overline{\text{NMI}}$				
18	16		P8_4	$\overline{\text{INT2}}$				
19	17		P8_3	$\overline{\text{INT1}}$				
20	18		P8_2	$\overline{\text{INT0}}$				
21	19		P8_1					
22	20		P8_0					
23	21		P7_7					
24	22		P7_6					
25	23		P7_5		TA2IN			
26	24		P7_4		TA2OUT			
27	25		P7_3		TA1IN	$\overline{\text{CTS2}}/\overline{\text{RTS2}}$		
28	26		P7_2		TA1OUT	CLK2		
29	27		P7_1		TA0IN	RXD2/SCL2		
30	28		P7_0		TA0OUT	TXD2/SDA2		
31	29		P6_7			TXD1/SDA1		
32	30		P6_6			RXD1/SCL1		
33	31		P6_5			CLK1		
34	32		P6_4			$\overline{\text{CTS1}}/\overline{\text{RTS1}}/\overline{\text{CTS0}}$/CLKS1		
35	33		P6_3			TXD0/SDA0		
36	34		P6_2			RXD0/SCL0		
37	35		P6_1			CLK0		
38	36		P6_0			$\overline{\text{CTS0}}/\overline{\text{RTS0}}$		
39	37		P5_7					$\overline{\text{RDY}}$/CLKOUT
40	38		P5_6					ALE
41	39		P5_5					$\overline{\text{HOLD}}$
42	40		P5_4					$\overline{\text{HLDA}}$
43	41		P5_3					BCLK
44	42		P5_2					$\overline{\text{RD}}$
45	43		P5_1					$\overline{\text{WRH}}/\overline{\text{BHE}}$
46	44		P5_0					$\overline{\text{WRL}}/\overline{\text{WR}}$
47	45		P4_7					$\overline{\text{CS3}}$
48	46		P4_6					$\overline{\text{CS2}}$
49	47		P4_5					$\overline{\text{CS1}}$
50	48		P4_4					$\overline{\text{CS0}}$

Table 1.7 Pin Characteristics (2)

Pin No.		Control Pin	Port	Interrupt Pin	Timer Pin	UART Pin	Analog Pin	Bus Control Pin
FP	GP							
51	49		P4_3					A19
52	50		P4_2					A18
53	51		P4_1					A17
54	52		P4_0					A16
55	53		P3_7					A15
56	54		P3_6					A14
57	55		P3_5					A13
58	56		P3_4					A12
59	57		P3_3					A11
60	58		P3_2					A10
61	59		P3_1					A9
62	60	VCC2						
63	61		P3_0					A8
64	62	VSS						
65	63		P2_7					A7
66	64		P2_6					A6
67	65		P2_5					A5
68	66		P2_4					A4
69	67		P2_3					A3
70	68		P2_2					A2
71	69		P2_1					A1
72	70		P2_0					A0
73	71		P1_7					D15
74	72		P1_6	$\overline{\text{INT4}}$				D14
75	73		P1_5	$\overline{\text{INT3}}$				D13
76	74		P1_4					D12
77	75		P1_3					D11
78	76		P1_2					D10
79	77		P1_1					D9
80	78		P1_0					D8
81	79		P0_7				AN0_7	D7
82	80		P0_6				AN0_6	D6
83	81		P0_5				AN0_5	D5
84	82		P0_4				AN0_4	D4
85	83		P0_3				AN0_3	D3
86	84		P0_2				AN0_2	D2
87	85		P0_1				AN0_1	D1
88	86		P0_0				AN0_0	D0
89	87		P10_7	$\overline{\text{KI3}}$			AN7	
90	88		P10_6	$\overline{\text{KI2}}$			AN6	
91	89		P10_5	$\overline{\text{KI1}}$			AN5	
92	90		P10_4	$\overline{\text{KI0}}$			AN4	
93	91		P10_3				AN3	
94	92		P10_2				AN2	
95	93		P10_1				AN1	
96	94	AVSS						
97	95		P10_0				AN0	
98	96	VREF						
99	97	AVCC						
100	98		P9_7				$\overline{\text{ADTRG}}$	

5. Electrical Characteristics

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter		Condition	Rated Value	Unit
V_{CC}	Supply Voltage(V_{CC1}=V_{CC2})		V_{CC1}=V_{CC2}=AVcc	–0.3 to 6.5	V
AVcc	Analog Supply Voltage		V_{CC1}=V_{CC2}=AVcc	–0.3 to 6.5	V
V_I	Input Voltage	$\overline{\text{RESET}}$, CNVSS, BYTE, P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_2 to P7_7, P8_0 to P8_7, P9_0 to P9_7, P10_0 to P10_7, VREF, XIN		–0.3 to V_{CC}+0.3	V
		P7_0, P7_1		–0.3 to 6.5	V
V_O	Output Voltage	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_2 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7, XOUT		–0.3 to V_{CC}+0.3	V
		P7_0, P7_1		–0.3 to 6.5	V
P_d	Power Dissipation		–40°C<T_{opr}≤85°C	300	mW
T_{opr}	Operating Ambient Temperature	When the Microcomputer is Operating		–20 to 85 / –40 to 85	°C
		One Time Flash Program Erase		0 to 60	
		Flash Program Erase		0 to 60	
T_{stg}	Storage Temperature			–65 to 150	°C

Table 5.2 Recommended Operating Conditions (1)

Symbol	Parameter		Standard			Unit
			Min.	Typ.	Max.	
V_{CC}	Supply Voltage (V_{CC1}=V_{CC2})		2.7	5.0	5.5	V
AVcc	Analog Supply Voltage			Vcc		V
Vss	Supply Voltage			0		V
AVss	Analog Supply Voltage			0		V
V_{IH}	HIGH Input Voltage	P3_1 to P3_7, P4_0 to P4_7, P5_0 to P5_7	0.8Vcc		Vcc	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 (during single-chip mode)	0.8Vcc		Vcc	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 (data input during memory expansion and microprocessor mode)	0.5Vcc		Vcc	V
		P6_0 to P6_7, P7_2 to P7_7, P8_0 to P8_7, P9_0 to P9_7, P10_0 to P10_7, XIN, $\overline{\text{RESET}}$, CNVSS, BYTE	0.8Vcc		Vcc	V
		P7_0, P7_1	0.8Vcc		6.5	V
V_{IL}	LOW Input Voltage	P3_1 to P3_7, P4_0 to P4_7, P5_0 to P5_7	0		0.2Vcc	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 (during single-chip mode)	0		0.2Vcc	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 (data input during memory expansion and microprocessor mode)	0		0.16Vcc	V
		P6_0 to P6_7, P7_0 to P7_7, P8_0 to P8_7, P9_0 to P9_7, XIN, $\overline{\text{RESET}}$, CNVSS, BYTE	0		0.2Vcc	V
$I_{OH(peak)}$	HIGH Peak Output Current	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_2 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7			−10.0	mA
$I_{OH(avg)}$	HIGH Average Output Current	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_2 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7			−5.0	mA
$I_{OL(peak)}$	LOW Peak Output Current	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7			10.0	mA
$I_{OL(avg)}$	LOW Average Output Current	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P6_0 to P6_7, P7_0 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7			5.0	mA
f(XIN)	Main Clock Input Oscillation Frequency (4)	Vcc=3.0V to 5.5V	0		16	MHz
		Vcc=2.7V to 3.0V	0		20×V_{CC1}−44	MHz
f(XCIN)	Sub-Clock Oscillation Frequency			32.768	50	kHz
f(BCLK)	CPU Operation Clock		0		16	MHz

NOTES:
1. Referenced to V_{CC1} = V_{CC2} = 2.7 to 5.5V at T_{opr} = −20 to 85°C / −40 to 85°C unless otherwise specified.
2. The Average Output Current is the mean value within 100ms.
3. The total $I_{OL(peak)}$ for ports P0, P1, P2, P8_6, P8_7, P9 and P10 must be 80mA max. The total $I_{OL(peak)}$ for ports P3, P4, P5, P6, P7 and P8_0 to P8_4 must be 80mA max. The total $I_{OH(peak)}$ for ports P0, P1, and P2 must be −40mA max. The total $I_{OH(peak)}$ for ports P3, P4 and P5 must be −40mA max. The total $I_{OH(peak)}$ for ports P6, P7, and P8_0 to P8_4 must be −40mA max.
   The total $I_{OH(peak)}$ for ports P8_6, P8_7 and P9 must be −40mA max. Set Average Output Current to 1/2 of peak.
4. Relationship between main clock oscillation frequency, and supply voltage.

Main clock input oscillation frequency

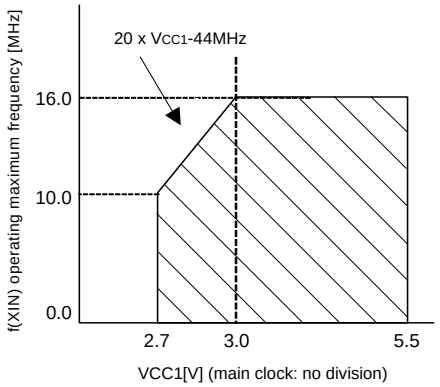


Table 5.3 A/D Conversion Characteristics (1)

Symbol	Parameter		Measuring Condition		Standard			Unit
					Min.	Typ.	Max.	
–	Resolution		$V_{REF}=V_{CC}$				10	Bits
INL	Integral Non-Linearity Error	10bit	$V_{REF}=V_{CC}=5V$	AN0 to AN7 input, AN0_0 to AN0_7 input, ANEX0, ANEX1 input			±5	LSB
			$V_{REF}=V_{CC}=3.3V$	AN0 to AN7 input, AN0_0 to AN0_7 input, ANEX0, ANEX1 input			±7	LSB
		8bit	$V_{REF}=V_{CC}=5V, 3.3V$				±2	LSB
–	Absolute Accuracy	10bit	$V_{REF}=V_{CC}=5V$	AN0 to AN7 input, AN0_0 to AN0_7 input, ANEX0, ANEX1 input			±5	LSB
			$V_{REF}=V_{CC}=3.3V$	AN0 to AN7 input, AN0_0 to AN0_7 input, ANEX0, ANEX1 input			±7	LSB
		8bit	$V_{REF}=V_{CC}=5V, 3.3V$				±2	LSB
–	Tolerance Level Impedance					3		kΩ
DNL	Differential Non-Linearity Error						±2	LSB
–	Offset Error						±5	LSB
–	Gain Error						±5	LSB
R_{LADDER}	Ladder Resistance		$V_{REF}=V_{CC}$		10		40	kΩ
t_{CONV}	10-bit Conversion Time, Sample & Hold Function Available		$V_{REF}=V_{CC}=5V$, ϕAD=10MHz		3.3			µs
t_{CONV}	8-bit Conversion Time, Sample & Hold Function Available		$V_{REF}=V_{CC}=5V$, ϕAD=10MHz		2.8			µs
t_{SAMP}	Sampling Time				0.3			µs
V_{REF}	Reference Voltage				3.0		V_{CC}	V
V_{IA}	Analog Input Voltage				0		V_{REF}	V

NOTES:
1. Referenced to $V_{CC}=AV_{CC}=V_{REF}=3.3$ to 5.5V, $V_{SS}=AV_{SS}=0V$ at T_{opr} = –20 to 85°C / –40 to 85°C unless otherwise specified.
2. ϕAD frequency must be 10 MHz or less.
3. When sample & hold function is disabled, ϕAD frequency must be 250 kHz or more, in addition to the limitation in Note 2.
4. When sample & hold function is enabled, ϕAD frequency must be 1MHz or more, in addition to the limitation in Note 2.

$V_{CC1}=V_{CC2}=5V$

Timing Requirements

(V_{CC1} = V_{CC2} = 5V, V_{SS} = 0V, at T_{opr} = –20 to 85°C / –40 to 85°C unless otherwise specified)

Table 5.11 External Clock Input (XIN input) (1)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t_c	External Clock Input Cycle Time	62.5		ns
$t_{w(H)}$	External Clock Input HIGH Pulse Width	25		ns
$t_{w(L)}$	External Clock Input LOW Pulse Width	25		ns
t_r	External Clock Rise Time		15	ns
t_f	External Clock Fall Time		15	ns

NOTES:
1. The condition is V_{CC1}=V_{CC2}=3.0 to 5.0V.

Table 5.12 Memory Expansion Mode and Microprocessor Mode

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{ac1(RD-DB)}$	Data Input Access Time (for setting with no wait)		(NOTE 1)	ns
$t_{ac2(RD-DB)}$	Data Input Access Time (for setting with wait)		(NOTE 2)	ns
$t_{su(DB-RD)}$	Data Input Setup Time	40		ns
$t_{su(RDY-BCLK)}$	$\overline{RDY}$ Input Setup Time	30		ns
$t_{su(HOLD-BCLK)}$	$\overline{HOLD}$ Input Setup Time	40		ns
$t_{h(RD-DB)}$	Data Input Hold Time	0		ns
$t_{h(BCLK-RDY)}$	$\overline{RDY}$ Input Hold Time	0		ns
$t_{h(BCLK-HOLD)}$	$\overline{HOLD}$ Input Hold Time	0		ns

NOTES:
1. Calculated according to the BCLK frequency as follows:

$$\frac{0.5 \times 10^9}{f(BCLK)} - 45[ns]$$

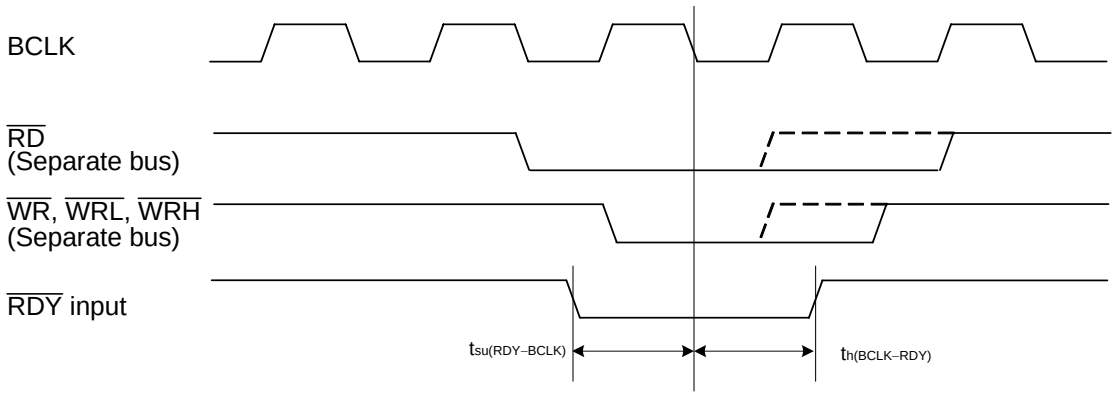
2. Calculated according to the BCLK frequency as follows:

$$\frac{(n - 0.5) \times 10^9}{f(BCLK)} - 45[ns]$$ n is "2" for 1-wait setting.

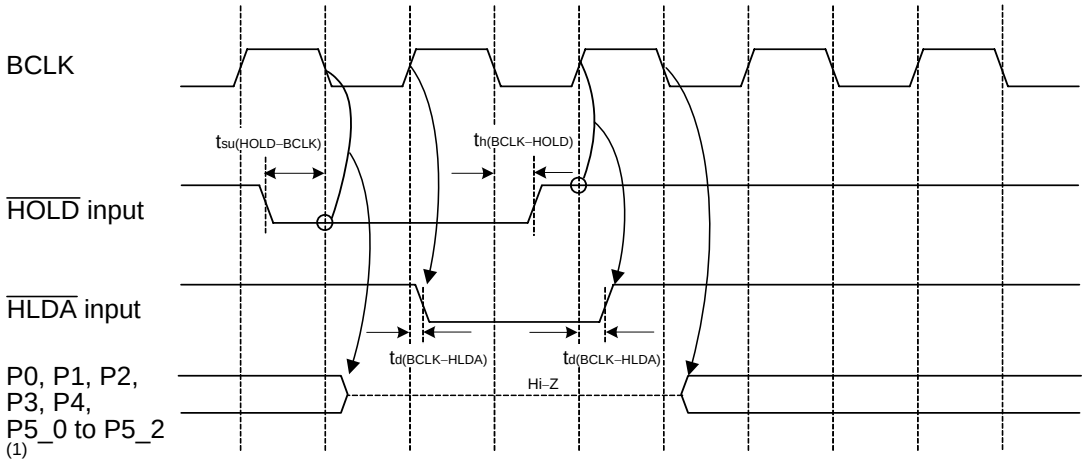
$V_{CC1}=V_{CC2}=5V$

Memory Expansion Mode, Microprocessor Mode

(Effective for setting with wait**)**



(Common to setting with wait and setting without wait**)**



NOTES:

1. These pins are set to high-impedance regardless of the input level of the BYTE pin, PM06 bit in PM0 register.

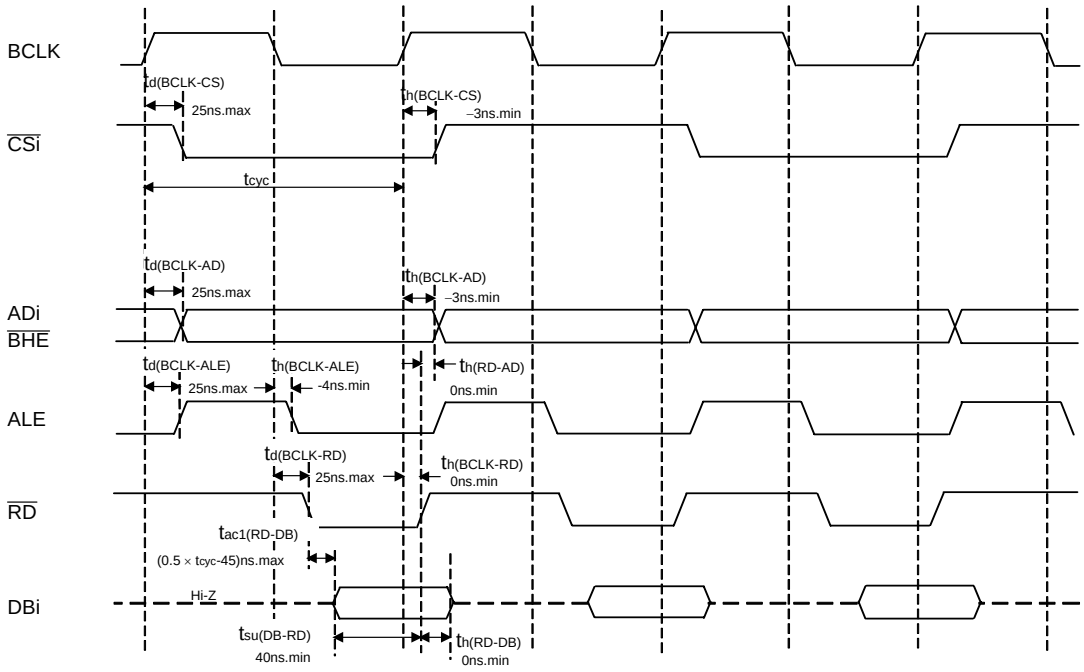
· Measuring conditions :
· $V_{CC1}=V_{CC2}=5V$
· Input timing voltage : Determined with $V_{IL}=1.0V$, $V_{IH}=4.0V$
· Output timing voltage : Determined with $V_{OL}=2.5V$, $V_{OH}=2.5V$

Figure 5.5 Timing Diagram (3)

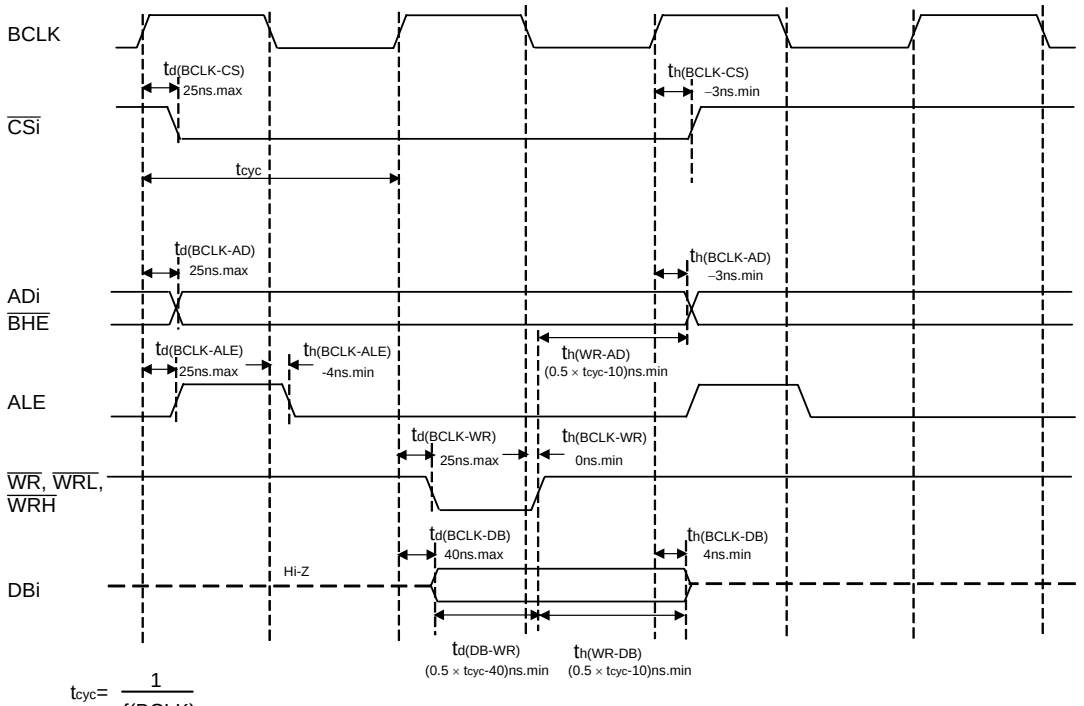
Memory Expansion Mode, Microprocessor Mode
(For setting with no wait**)**

$V_{CC1}=V_{CC2}=5V$

Read timing



Write timing



$$t_{cyc}=\frac{1}{f(BCLK)}$$

Measuring conditions
· $V_{CC1}=V_{CC2}=5V$
· Input timing voltage : $V_{IL}=0.8V$, $V_{IH}=2.0V$
· Output timing voltage : $V_{OL}=0.4V$, $V_{OH}=2.4V$

Figure 5.6 Timing Diagram (4)

Table 5.28 Electrical Characteristics (2) (1)

Symbol	Parameter		Measuring Condition		Standard			Unit
					Min.	Typ.	Max.	
I_{CC}	Power Supply Current (V_{CC1}=V_{CC2}=2.7V to 3.6V)	In single-chip mode, the output pins are open and other pins are V_{SS}	Mask ROM	f(XIN)=10MHz No division		8	11	mA
			One Time Flash	f(XIN)=10MHz, No division		8	13	mA
			Flash Memory	f(XIN)=10MHz, No division		8	13	mA
			Flash Memory Program	f(XIN)=10MHz, VCC1=3.0V		12		mA
			One Time Flash Program	f(XIN)=10MHz, VCC1=3.0V		12		mA
			Flash Memory Erase	f(XIN)=10MHz, VCC1=3.0V		22		mA
			Mask ROM	f(XCIN)=32kHz Low power dissipation mode, ROM (3)		25		µA
			One Time Flash	f(XCIN)=32kHz Low power dissipation mode, RAM (3)		25		µA
				f(XCIN)=32kHz Low power dissipation mode, Flash Memory (3)		350		µA
			Flash Memory	f(XCIN)=32kHz Low power dissipation mode, RAM (3)		25		µA
				f(XCIN)=32kHz Low power dissipation mode, Flash Memory (3)		420		µA
			Mask ROM One Time Flash Flash Memory	f(XCIN)=32kHz Wait mode (2), Oscillation capability High		6.0		µA
				f(XCIN)=32kHz Wait mode (2), Oscillation capability Low		1.8		µA
				Stop mode Topr =25°C		0.7	3.0	µA

NOTES:
1. Referenced to V_{CC1}=V_{CC2}=2.7 to 3.3V, V_{SS} = 0V at T_{opr} = –20 to 85°C / –40 to 85°C, f(XIN)=10MHz unless otherwise specified.
2. With one timer operated using fC32.
3. This indicates the memory in which the program to be executed exists.

$V_{CC1}=V_{CC2}=3V$

Timing Requirements
(V_{CC1} = V_{CC2} = 3V, V_{SS} = 0V, at T_{opr} = –20 to 85°C / –40 to 85°C unless otherwise specified)

Table 5.31 Timer A Input (Counter Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	150		ns
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	60		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	60		ns

Table 5.32 Timer A Input (Gating Input in Timer Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	600		ns
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	300		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	300		ns

Table 5.33 Timer A Input (External Trigger Input in One-shot Timer Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	300		ns
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	150		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	150		ns

Table 5.34 Timer A Input (External Trigger Input in Pulse Width Modulation Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	150		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	150		ns

Table 5.35 Timer A Input (Counter Increment/Decrement Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(UP)}$	TAiOUT Input Cycle Time	3000		ns
$t_{w(UPH)}$	TAiOUT Input HIGH Pulse Width	1500		ns
$t_{w(UPL)}$	TAiOUT Input LOW Pulse Width	1500		ns
$t_{su(UP-TIN)}$	TAiOUT Input Setup Time	600		ns
$t_{h(TIN-UP)}$	TAiOUT Input Hold Time	600		ns

Table 5.36 Timer A Input (Two-phase Pulse Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	2		µs
$t_{su(TAIN-TAOUT)}$	TAiOUT Input Setup Time	500		ns
$t_{su(TAOUT-TAIN)}$	TAiIN Input Setup Time	500		ns

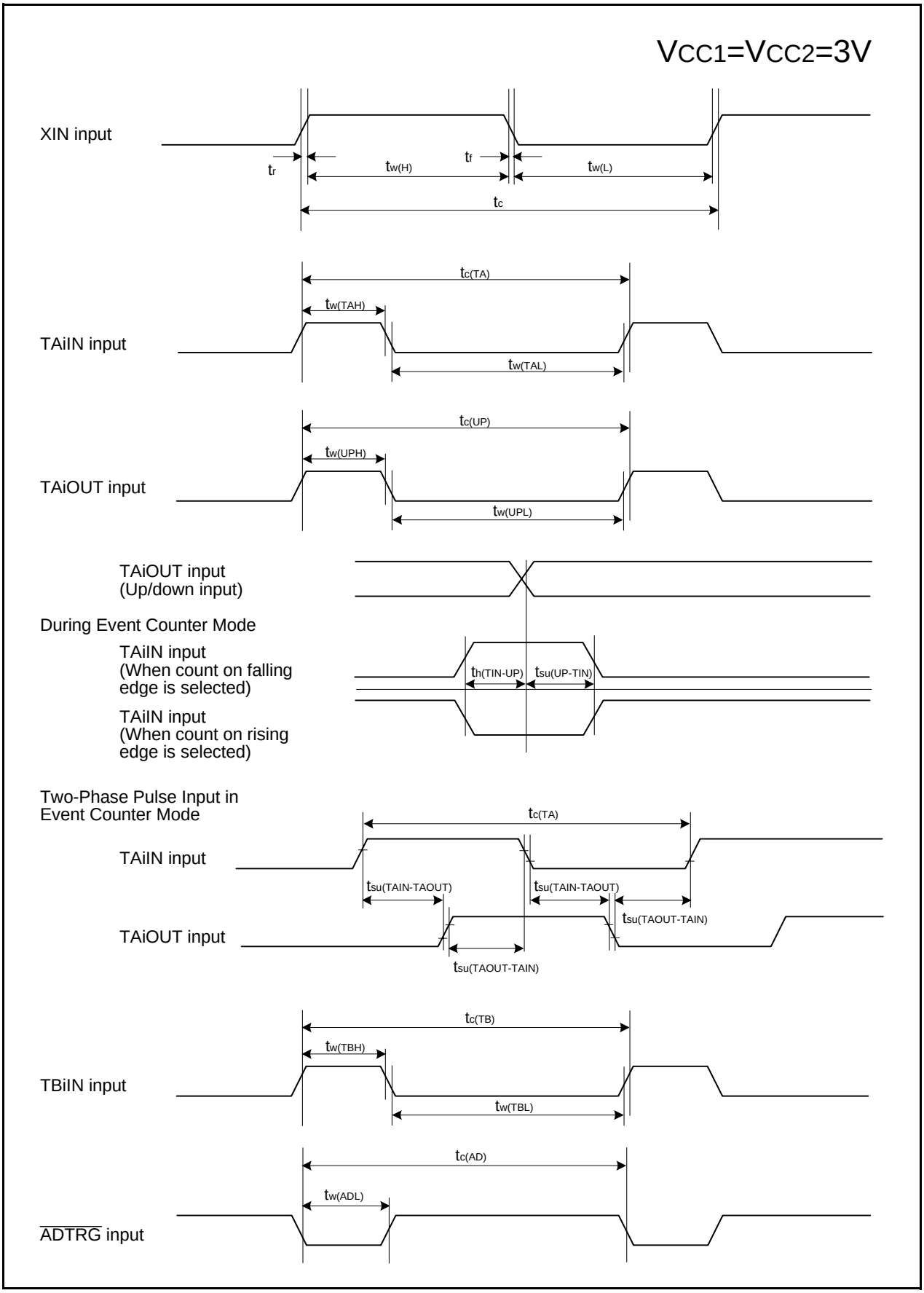


Figure 5.9 Timing Diagram (1)

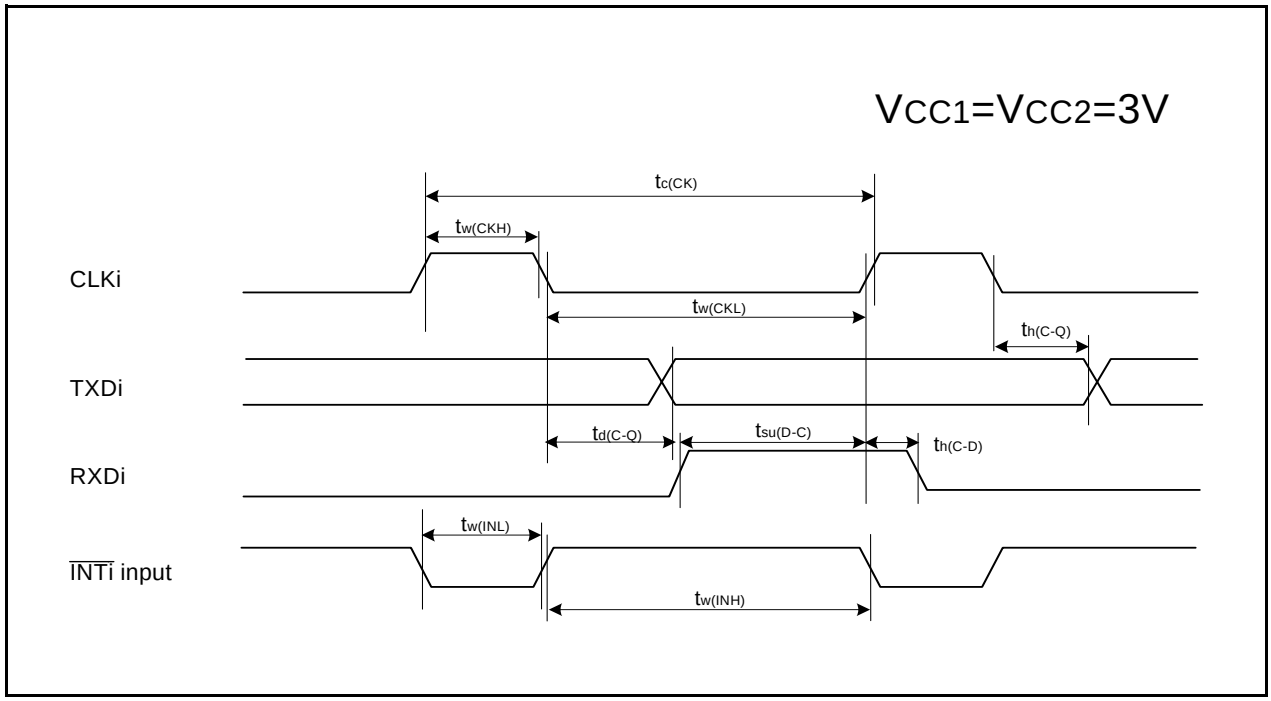
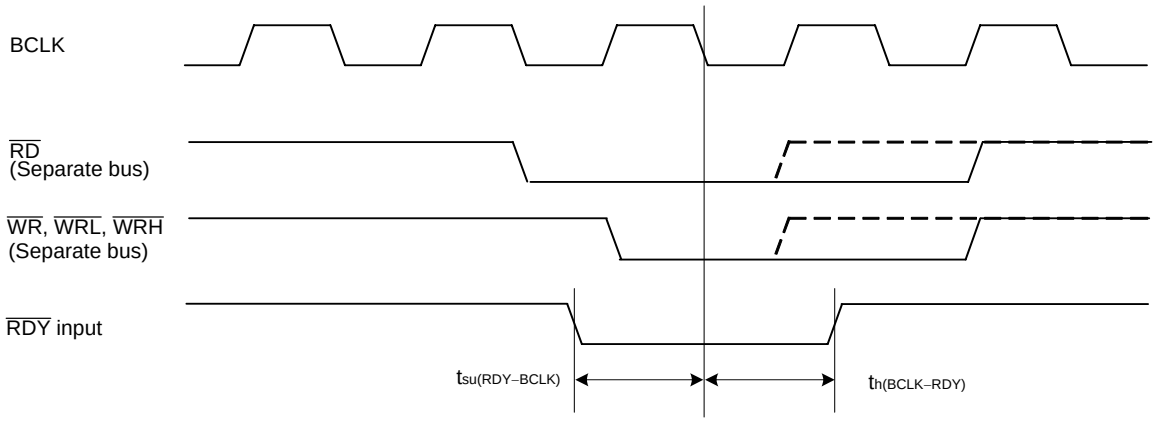


Figure 5.10 Timing Diagram (2)

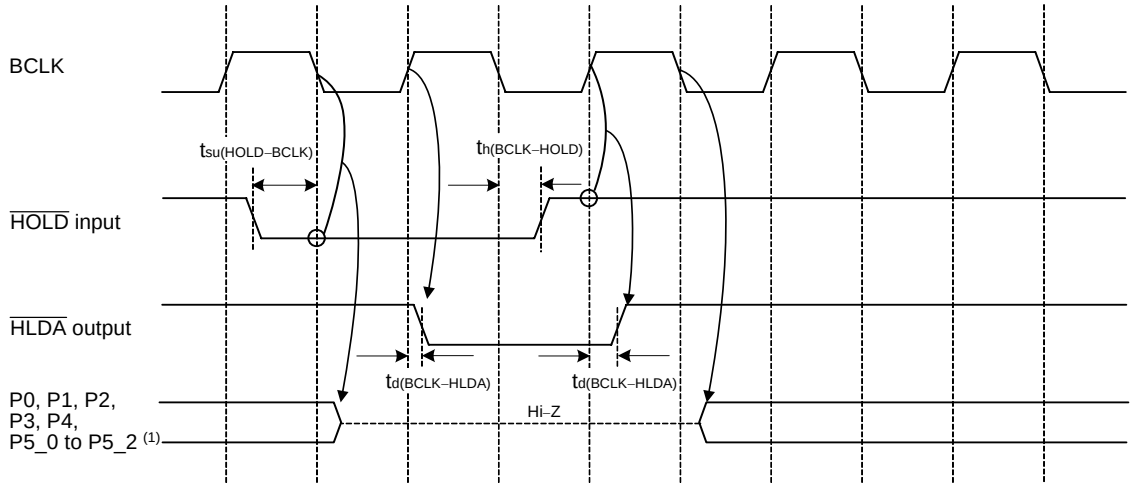
Memory Expansion Mode, Microprocessor Mode

$V_{CC1}=V_{CC2}=3V$

(Effective for setting with wait)



(Common to setting with wait and setting without wait)



NOTES:
1. These pins are set to high-impedance regardless of the input level of the BYTE pin, PM06 bit in PM0 register.

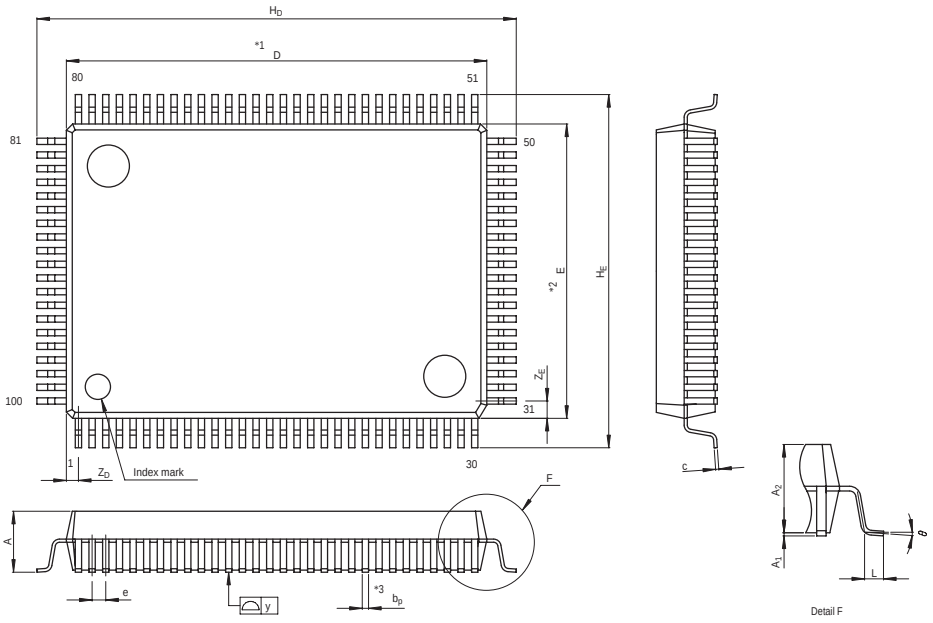
Measuring conditions :
· $V_{CC1}=V_{CC2}=3V$
· Input timing voltage : Determined with $V_{IL}=0.6V$, $V_{IH}=2.4V$
· Output timing voltage : Determined with $V_{OL}=1.5V$, $V_{OH}=1.5V$

Figure 5.11 Timing Diagram (3)

Appendix 1. Package Dimensions

Diagrams showing the latest package dimensions and mounting information are available in the "Packages" section of the Renesas Technology website.

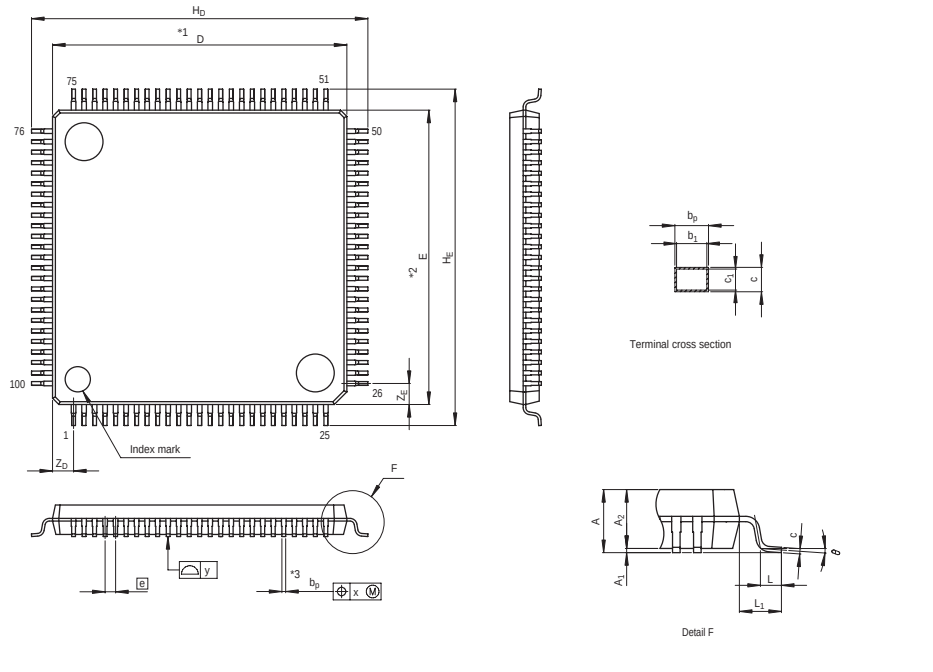
JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-QFP100-14x20-0.65	PRQP0100JB-A	100P6S-A	1.6g



NOTE)
1. DIMENSIONS "*1" AND "*2" DO NOT INCLUDE MOLD FLASH.
2. DIMENSION "*3" DOES NOT INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	19.8	20.0	20.2
E	13.8	14.0	14.2
A_2	—	2.8	—
H_D	22.5	22.8	23.1
H_E	16.5	16.8	17.1
A	—	—	3.05
A_1	0	0.1	0.2
b_p	0.25	0.3	0.4
c	0.13	0.15	0.2
θ	0°	—	10°
e	0.5	0.65	0.8
y	—	—	0.10
Z_D	—	0.575	—
Z_E	—	0.825	—
L	0.4	0.6	0.8

JEITA Package Code	RENESAS Code	Previous Code	MASS[Typ.]
P-LQFP100-14x14-0.50	PLQP0100KB-A	100P6Q-A / FP-100U / FP-100UV	0.6g



NOTE)
1. DIMENSIONS "*1" AND "*2" DO NOT INCLUDE MOLD FLASH.
2. DIMENSION "*3" DOES NOT INCLUDE TRIM OFFSET.

Reference Symbol	Dimension in Millimeters		
	Min	Nom	Max
D	13.9	14.0	14.1
E	13.9	14.0	14.1
A_2	—	1.4	—
H_D	15.8	16.0	16.2
H_E	15.8	16.0	16.2
A	—	—	1.7
A_1	0.05	0.1	0.15
b_p	0.15	0.20	0.25
b_1	—	0.18	—
c	0.09	0.145	0.20
c_1	—	0.125	—
θ	0°	—	8°
e	—	0.5	—
x	—	—	0.08
y	—	—	0.08
Z_D	—	1.0	—
Z_E	—	1.0	—
L	0.35	0.5	0.65
L_1	—	1.0	—

REVISION HISTORY	M16C/30P Group Datasheet

Rev.	Date	Description	
		Page	Summary
0.70	Aug 26, 2004	–	First Edition issued
0.80	Mar 18, 2005	–	development support tools -> development tools
		–	BCLK -> CPU clock
		2	Table 1.1 Performance Outline of M16C/30P Group Serial interface is revised.
		4	Figure 1.2 Type., Memory Size, and Package is partly revised.
		8	Table 1.4 Pin Detection (2) is partly revised.
		20	Note 2 Table 5.3 A/D Conversion Characteristics is partly revised.
		21	Symbol of Table 5.4 Power Supply Circuit Timing Characteristics is partly revised.
		22	Table 5.5 Electrical Characteristics is revised.
		28	Table 5.19 Electrical Characteristics is revised.
1.00	Sep 01, 2005	2	Table 1.1 Performance Outline of M16C/30P Group is partly revised.
		4	Table 1.2 Product List is partly revised.
			Figure 1.2 Type No., Memory Size, and Package is partly revised.
		5	Figure 1.3 Pin Configuration is partly revised.
		6	Figure 1.4 Pin Configuration is partly revised.
		7-8	Tables 1.3 to 1.4 Pin Characteristics are added.
		9	Table 1.5 Pin Description is revised.
		14	3. Memory is partly revised.
		15	Table 4.1 SFR Information is partly revised.
		19	Table 4.5 SFR Information is partly revised
		21	Table 5.2 Recommended Operating Conditions is partly revised.
		22	Table 5.3 A/D Conversion Characteristics is partly revised.
		25	Note 1 is added in Table 5.6 External Clock Input (XIN input)
			Table 5.7 Memory Expansion Mode and Microprocessor Mode is added.
		28	Table 5.20 Memory Expansion Mode and Microprocessor Modes (for setting with no wait) is added.
			Figure 5.2 Ports P0 to P10 Measurement Circuit is added.
		29	Table 5.21 Memory Expansion Mode and Microprocessor Modes (for 1- to 3-wait setting and external area access) is added.
		32	Figure 5.5 Timing Diagram (3) is added.
		33	Figure 5.6 Timing Diagram (4) is added.
		34	Figure 5.7 Timing Diagram (5) is added.
		36	Note 1 to 4 are added in Table 5.23 External Clock Input (XIN input)
			Table 5.24 Memory Expansion Mode and Microprocessor Mode is added.
		39	Table 5.37 Memory Expansion Mode and Microprocessor Modes (for setting with no wait) is added.
			Figure 5.8 Ports P0 to P10 Measurement Circuit is added.
		40	Table 5.38 Memory Expansion Mode and Microprocessor Modes (for 1- to 3-wait setting and external area access) is added.
		43	Figure 5.11 Timing Diagram (3) is added.

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